

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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• 1N6639US THRU 1N6641US AVAILABLE IN JAN, JANTX, JANTXV AND JANS PER MIL-PRF-19500/609

SWITCHING DIODES

• NON-CAVITY GLASS PACKAGE

METALLURGICALLY BONDED

1N6639US 1N6640US 1N6641US

MAXIMUM RATINGS

Operating Temperature: -65°C to +175°C Storage Temperature: -65°C to +175°C

Operating Current: 300 mA

Derating: 4.6 mA/°C Above T_{EC} = + 110°C Surge Current: I_{FSM} = 2.5A, P_W = 8.3ms

ELECTRICAL CHARACTERISTICS @ 25°C, unless otherwise speci1/2ed.

TYPES	V BRR @ 10 μA	V RWM	I _{R1} @T _A = +25°C V _R = V _{RWM}	I _{R2} @ T _A = +150°C V _R = V RWM	T FR IF = 200 mA	T _{RR} I _R = 10 mA I _F = 10 mA R _L = 100	C _T V _R = 0
	V _(pk)	V _(pk)	nA dc	μA dc	ns	ns	pF
1N6639US 1N6640US 1N6641US	100 75 75	75 50 50	100 100 100	100 100 100	10 10 10	4.0 4.0 5.0	2.5 2.5 3.0

FORWARD VOLTAGE:

	V _{F @} I _F				
TYPES	Vo	IC	mA		
	MIN	MAX	(PULSED)		
1N6639US	-	1.20	500		
	0.54	0.62	1		
1N6640US	0.76	0.86	50		
	0.82	0.92	100		
	0.87	1.00	200		
1N6641US	-	1.10	200		

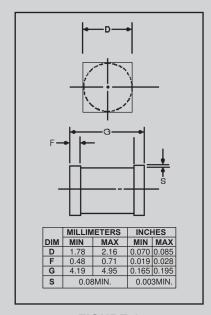


FIGURE 1

DESIGN DATA

CASE: D-5D, Hermetically sealed glass case, per MIL-PRF- 19500/609

LEAD FINISH: Tin / Lead

THERMAL RESISTANCE: (R_QJEC): 50 °C/W maximum at L = 0

THERMAL IMPEDANCE: (∠_{OJX}): 25 °C/W maximum

POLARITY: Cathode end is banded

MOUNTING SURFACE SELECTION:

The Axial Coefficient of Expansion (COE) of this device is approximately + 4PPM / °C. The COE of the Mounting Surface System should be selected to provide a suitable match with this device.



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IN6639US thru IN6641US

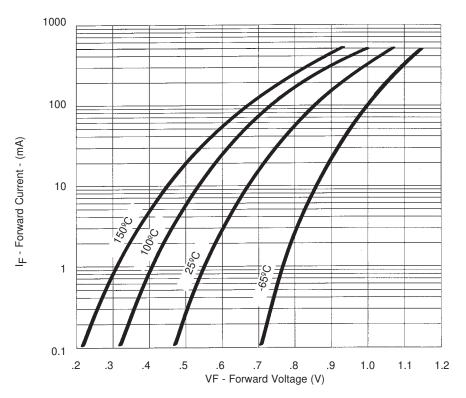


FIGURE 2
Typical Forward Current vs Forward Voltage

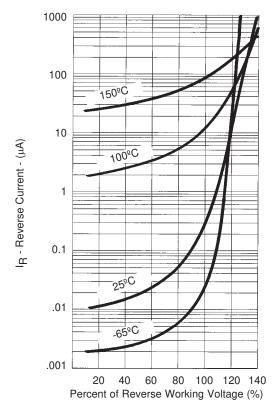


FIGURE 3
Typical Reverse Current
vs Reverse Voltage

NOTE: All temperatures shown on graphs are junction temperatures